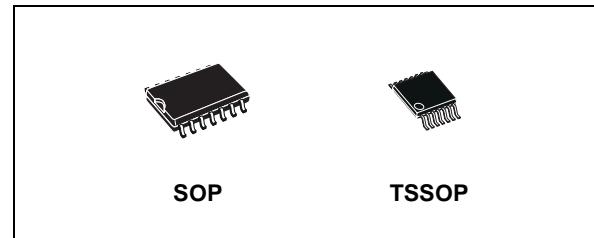


DUAL D-TYPE FLIP FLOP WITH PRESET AND CLEAR

- HIGH SPEED:
 $f_{MAX} = 250$ MHz (TYP.) at $V_{CC} = 3.3V$
- COMPATIBLE WITH TTL OUTPUTS
- LOW POWER DISSIPATION:
 $I_{CC} = 2 \mu A$ (MAX.) at $T_A = 25^\circ C$
- LOW NOISE:
 $V_{OLP} = 0.2 V$ (TYP.) at $V_{CC} = 3.3V$
- 75Ω TRANSMISSION LINE DRIVING CAPABILITY
- SYMMETRICAL OUTPUT IMPEDANCE:
 $|I_{OHI}| = I_{OL} = 12mA$ (MIN) at $V_{CC} = 3.0V$
- PCI BUS LEVELS GUARANTEED AT 24 mA
- BALANCED PROPAGATION DELAYS:
 $t_{PLH} \approx t_{PHL}$
- OPERATING VOLTAGE RANGE:
 $V_{CC(OPR)} = 2V$ to $3.6V$ (1.2V Data Retention)
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 74
- IMPROVED LATCH-UP IMMUNITY

DESCRIPTION

The 74LVQ74 is a low voltage CMOS DUAL D-TYPE FLIP FLOP WITH PRESET AND CLEAR NON INVERTING fabricated with sub-micron silicon gate and double-layer metal wiring C²MOS



ORDER CODES

| PACKAGE | TUBE | T & R |
|---------|----------|------------|
| SOP | 74LVQ74M | 74LVQ74MTR |
| TSSOP | | 74LVQ74TTR |

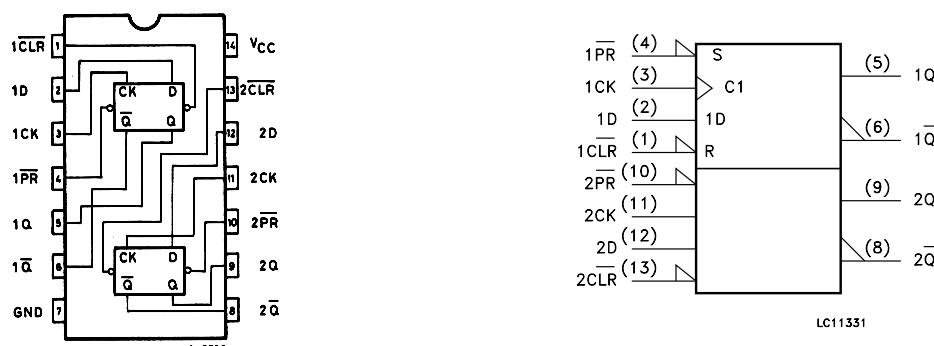
technology. It is ideal for low power and low noise 3.3V applications.

A signal on the D INPUT is transferred to the Q OUTPUT during the positive going transition of the clock pulse.

CLEAR and PRESET are independent of the clock and accomplished by a low setting on the appropriate input.

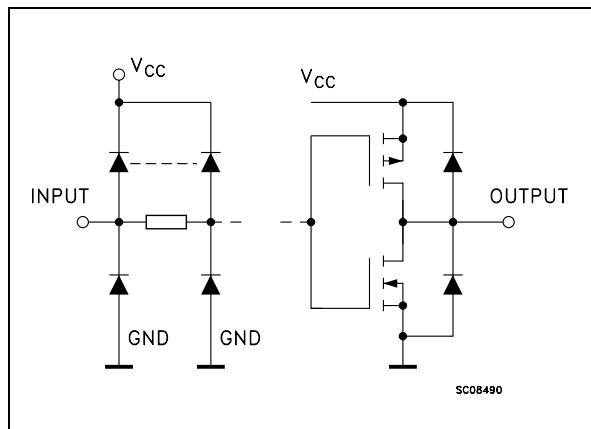
All inputs and outputs are equipped with protection circuits against static discharge, giving them 2KV ESD immunity and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



74LVQ74

INPUT AND OUTPUT EQUIVALENT CIRCUIT



PIN DESCRIPTION

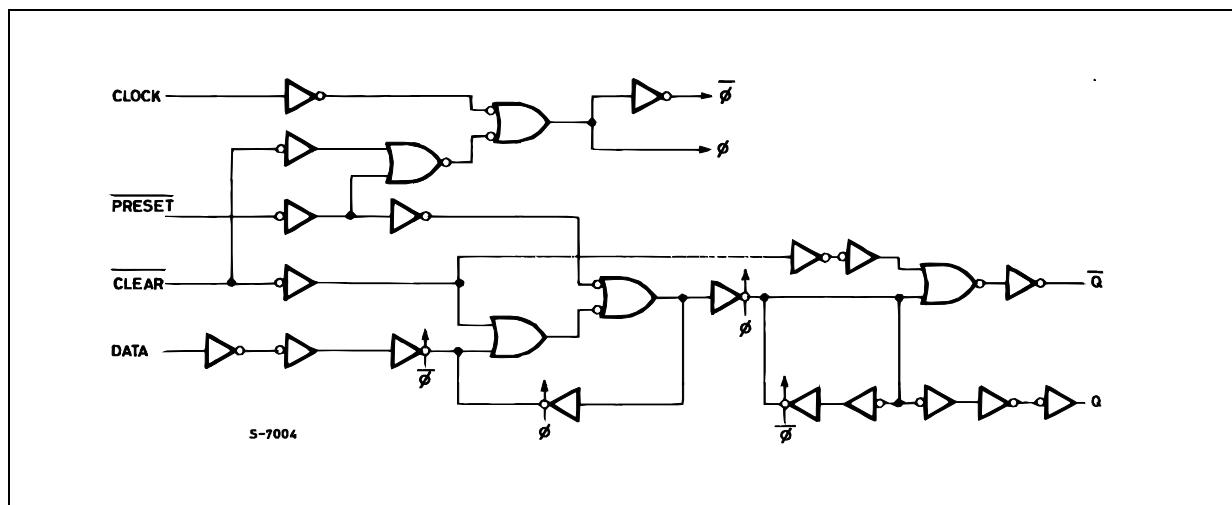
| PIN No | SYMBOL | NAME AND FUNCTION |
|--------|------------------------------------|---|
| 1, 13 | $\overline{1CLR}, \overline{2CLR}$ | Asynchronous Reset - Direct Input |
| 2, 12 | 1D, 2D | Data Inputs |
| 3, 11 | 1CK, 2CK | Clock Input (LOW to HIGH, Edge Triggered) |
| 4, 10 | 1PR, 2PR | Asynchronous Set - Direct Input |
| 5, 9 | 1Q, 2Q | True Flip-Flop Outputs |
| 6, 8 | $\overline{1Q}, \overline{2Q}$ | Complement Flip-Flop Outputs |
| 7 | GND | Ground (0V) |
| 14 | V _{CC} | Positive Supply Voltage |

TRUTH TABLE

| INPUTS | | | | OUTPUTS | | FUNCTION |
|------------------|-----------------|---|----------------------|---------|------------------|-----------|
| \overline{CLR} | \overline{PR} | D | CK | Q | \overline{Q} | |
| L | H | X | X | L | H | CLEAR |
| H | L | X | X | H | L | PRESET |
| L | L | X | X | H | H | |
| H | H | L | $\overline{\square}$ | L | H | |
| H | H | H | $\overline{\square}$ | H | L | |
| H | H | X | $\overline{\square}$ | Q_n | \overline{Q}_n | NO CHANGE |

X : Don't Care

LOGIC DIAGRAM



This logic diagram has not be used to estimate propagation delays

ABSOLUTE MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|-----------------------|-------------------------------|------------------------|------|
| V_{CC} | Supply Voltage | -0.5 to +7 | V |
| V_I | DC Input Voltage | -0.5 to $V_{CC} + 0.5$ | V |
| V_O | DC Output Voltage | -0.5 to $V_{CC} + 0.5$ | V |
| I_{IK} | DC Input Diode Current | ± 20 | mA |
| I_{OK} | DC Output Diode Current | ± 20 | mA |
| I_O | DC Output Current | ± 50 | mA |
| I_{CC} or I_{GND} | DC V_{CC} or Ground Current | ± 400 | mA |
| T_{stg} | Storage Temperature | -65 to +150 | °C |
| T_L | Lead Temperature (10 sec) | 300 | °C |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | Value | Unit |
|----------|---|---------------|------|
| V_{CC} | Supply Voltage (note 1) | 2 to 3.6 | V |
| V_I | Input Voltage | 0 to V_{CC} | V |
| V_O | Output Voltage | 0 to V_{CC} | V |
| T_{op} | Operating Temperature | -55 to 125 | °C |
| dt/dv | Input Rise and Fall Time $V_{CC} = 3.0V$ (note 2) | 0 to 10 | ns/V |

1) Truth Table guaranteed: 1.2V to 3.6V

2) V_{IN} from 0.8V to 2V

DC SPECIFICATIONS

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|-----------|------------------------------------|-----------------|-----------------------|--------------------|-------|-----------|------------------------------|---------|-------------------------------|---------|----|
| | | V_{CC} (V) | | $T_A = 25^\circ C$ | | | $-40 \text{ to } 85^\circ C$ | | $-55 \text{ to } 125^\circ C$ | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | Max. | |
| V_{IH} | High Level Input Voltage | 3.0 to 3.6 | | 2.0 | | | 2.0 | | 2.0 | | V |
| V_{IL} | Low Level Input Voltage | | | | | 0.8 | | 0.8 | | 0.8 | V |
| V_{OH} | High Level Output Voltage | 3.0 | $I_O = -50 \mu A$ | 2.9 | 2.99 | | 2.9 | | 2.9 | | V |
| | | | $I_O = -12 mA$ | 2.58 | | | 2.48 | | 2.48 | | |
| | | | $I_O = -24 mA$ | | | | 2.2 | | 2.2 | | |
| V_{OL} | Low Level Output Voltage | 3.0 | $I_O = 50 \mu A$ | | 0.002 | 0.1 | | 0.1 | | 0.1 | V |
| | | | $I_O = 12 mA$ | | 0 | 0.36 | | 0.44 | | 0.44 | |
| | | | $I_O = 24 mA$ | | | | | 0.55 | | 0.55 | |
| I_I | Input Leakage Current | 3.6 | $V_I = V_{CC}$ or GND | | | ± 0.1 | | ± 1 | | ± 1 | µA |
| I_{CC} | Quiescent Supply Current | 3.6 | $V_I = V_{CC}$ or GND | | | 2 | | 20 | | 20 | µA |
| I_{OLD} | Dynamic Output Current (note 1, 2) | 3.6 | $V_{OLD} = 0.8 V$ max | | | 36 | | 25 | | 25 | mA |
| | | | $V_{OHD} = 2 V$ min | | | -25 | | -25 | | -25 | mA |

1) Maximum test duration 2ms, one output loaded at time

2) Incident wave switching is guaranteed on transmission lines with impedances as low as 75Ω

74LVQ74

DYNAMIC SWITCHING CHARACTERISTICS

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|------------------|--|------------------------|------------------------|-----------------------|------|------|-------------|------|--------------|------|---|
| | | V _{CC} (V) | C _L = 50 pF | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | Max. | |
| V _{OLP} | Dynamic Low Voltage Quiet Output (note 1, 2) | 3.3 | C _L = 50 pF | | 0.2 | 0.8 | | | | | V |
| V _{OLV} | | | | -0.8 | -0.2 | | | | | | |
| V _{IHD} | Dynamic High Voltage Input (note 1, 3) | | | 2 | | | | | | | |
| V _{ILD} | Dynamic Low Voltage Input (note 1, 3) | | | | | 0.8 | | | | | |

1) Worst case package.

2) Max number of outputs defined as (n). Data inputs are driven 0V to 3.3V, (n-1) outputs switching and one output at GND.

3) Max number of data inputs (n) switching. (n-1) switching 0V to 3.3V. Inputs under test switching: 3.3V to threshold (V_{ILD}), 0V to threshold (V_{IHD}), f=1MHz.

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, R_L = 500 Ω, Input t_r = t_f = 3ns)

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | |
|--|---------------------------------------|------------------------|------------------------|-----------------------|------|------|-------------|------|--------------|------|-----|
| | | V _{CC} (V) | C _L = 50 pF | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | Max. | |
| t _{PLH} t _{PHL} | Propagation Delay Time CK to Q | 2.7 | C _L = 50 pF | | 7.7 | 12.0 | | 14.0 | | 16.0 | ns |
| | | 3.3(*) | | | 6.3 | 9.0 | | 10.5 | | 12.0 | |
| t _{PLH} t _{PHL} | Propagation Delay Time PR or CLR to Q | 2.7 | C _L = 50 pF | | 6.9 | 12.0 | | 14.0 | | 16.0 | ns |
| | | 3.3(*) | | | 5.8 | 9.0 | | 10.5 | | 12.0 | |
| t _w | Pulse Width CK , HIGH or LOW | 2.7 | C _L = 50 pF | 4.0 | 1.5 | | 4.0 | | 5.0 | | ns |
| | | 3.3(*) | | 3.0 | 1.5 | | 3.0 | | 4.0 | | |
| t _{w(L)} | Pulse Width PR or CLR, LOW | 2.7 | C _L = 50 pF | 4.0 | 1.5 | | 4.0 | | 5.0 | | ns |
| | | 3.3(*) | | 3.0 | 1.5 | | 3.0 | | 4.0 | | |
| t _s | Setup Time D to CK HIGH or LOW | 2.7 | C _L = 50 pF | 4.0 | -0.2 | | 4.0 | | 5.0 | | ns |
| | | 3.3(*) | | 3.0 | -0.2 | | 3.0 | | 4.0 | | |
| t _h | Hold Time D to CK HIGH or LOW | 2.7 | C _L = 50 pF | 2.0 | 0.2 | | 2.0 | | 2.0 | | ns |
| | | 3.3(*) | | 2.0 | 0.2 | | 2.0 | | 2.0 | | |
| t _{REM} | Recovery Time PR or CLR to Q | 2.7 | C _L = 50 pF | 1.0 | -1.0 | | 1.0 | | 1.0 | | ns |
| | | 3.3(*) | | 1.0 | -1.0 | | 1.0 | | 1.0 | | |
| f _{MAX} | Maximum Clock Frequency | 2.7 | C _L = 50 pF | 100 | 200 | | 100 | | 80 | | MHz |
| | | 3.3(*) | | 120 | 250 | | 120 | | 100 | | |
| t _{OSLH} t _{OSHL} | Output To Output Skew Time (note1, 2) | 2.7 | C _L = 50 pF | | 0.2 | 1.0 | | 1.0 | | 1.0 | ns |
| | | 3.3(*) | | | 0.2 | 1.0 | | 1.0 | | 1.0 | |

1) Skew is defined as the absolute value of the difference between the actual propagation delay for any two outputs of the same device switching in the same direction, either HIGH or LOW (t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)

2) Parameter guaranteed by design

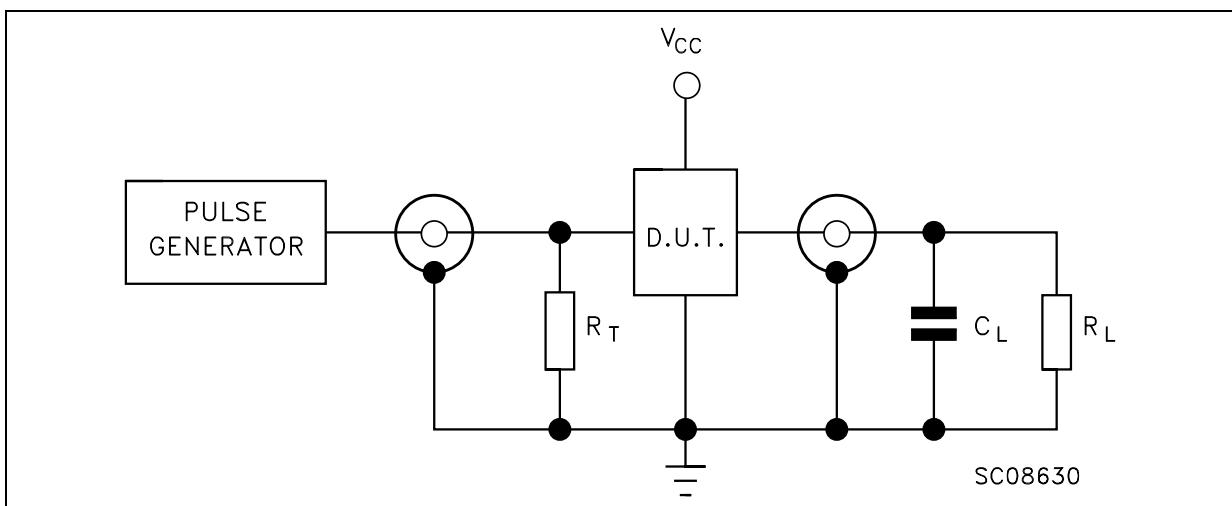
(*) Voltage range is 3.3V ± 0.3V

CAPACITIVE CHARACTERISTICS

| Symbol | Parameter | Test Condition | | Value | | | | | | Unit | | |
|-----------------|--|------------------------|-------------------------|-----------------------|------|------|-------------|------|--------------|------|--|--|
| | | V _{CC} (V) | | T _A = 25°C | | | -40 to 85°C | | -55 to 125°C | | | |
| | | | | Min. | Typ. | Max. | Min. | Max. | Min. | | | |
| C _{IN} | Input Capacitance | 3.3 | | | 4 | | | | | pF | | |
| C _{PD} | Power Dissipation Capacitance (note 1) | 3.3 | f _{IN} = 10MHz | | 33 | | | | | pF | | |

1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. I_{CC(opr)} = C_{PD} × V_{CC} × f_{IN} + I_{CC}/n (per circuit)

TEST CIRCUIT

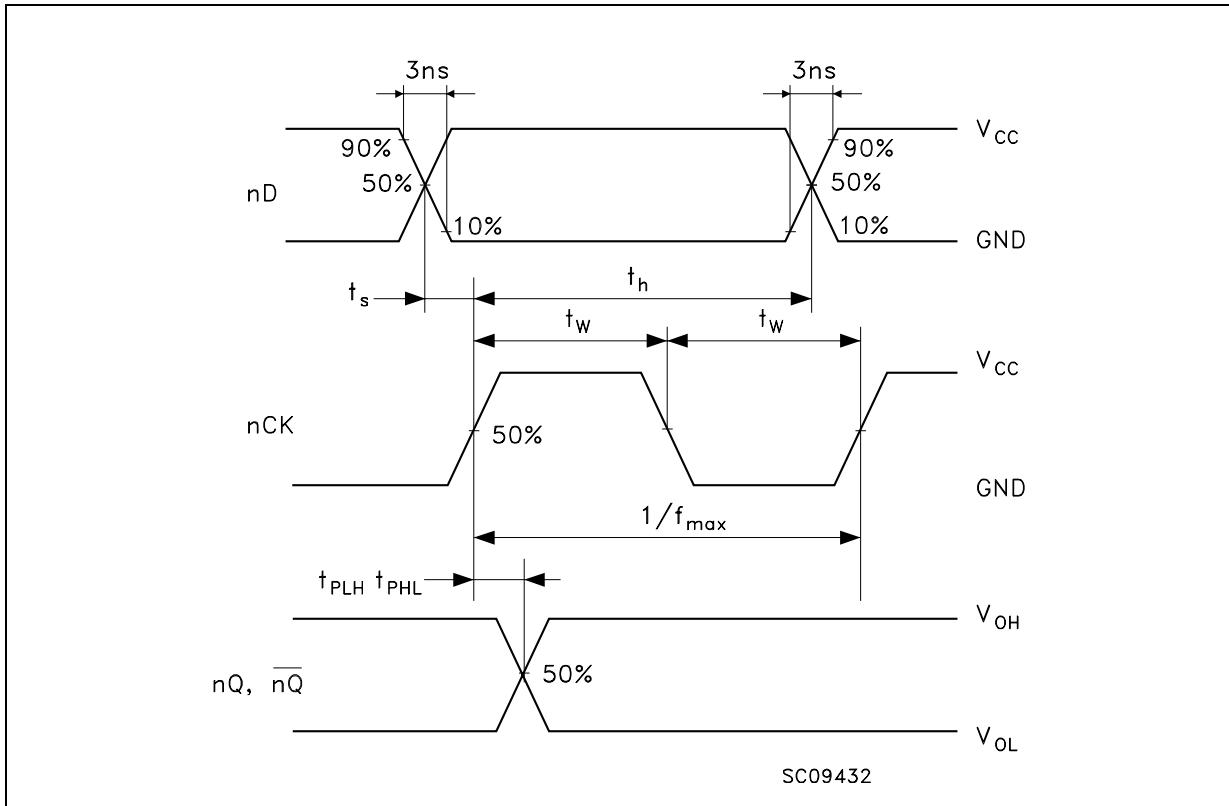


C_L = 50pF or equivalent (includes jig and probe capacitance)

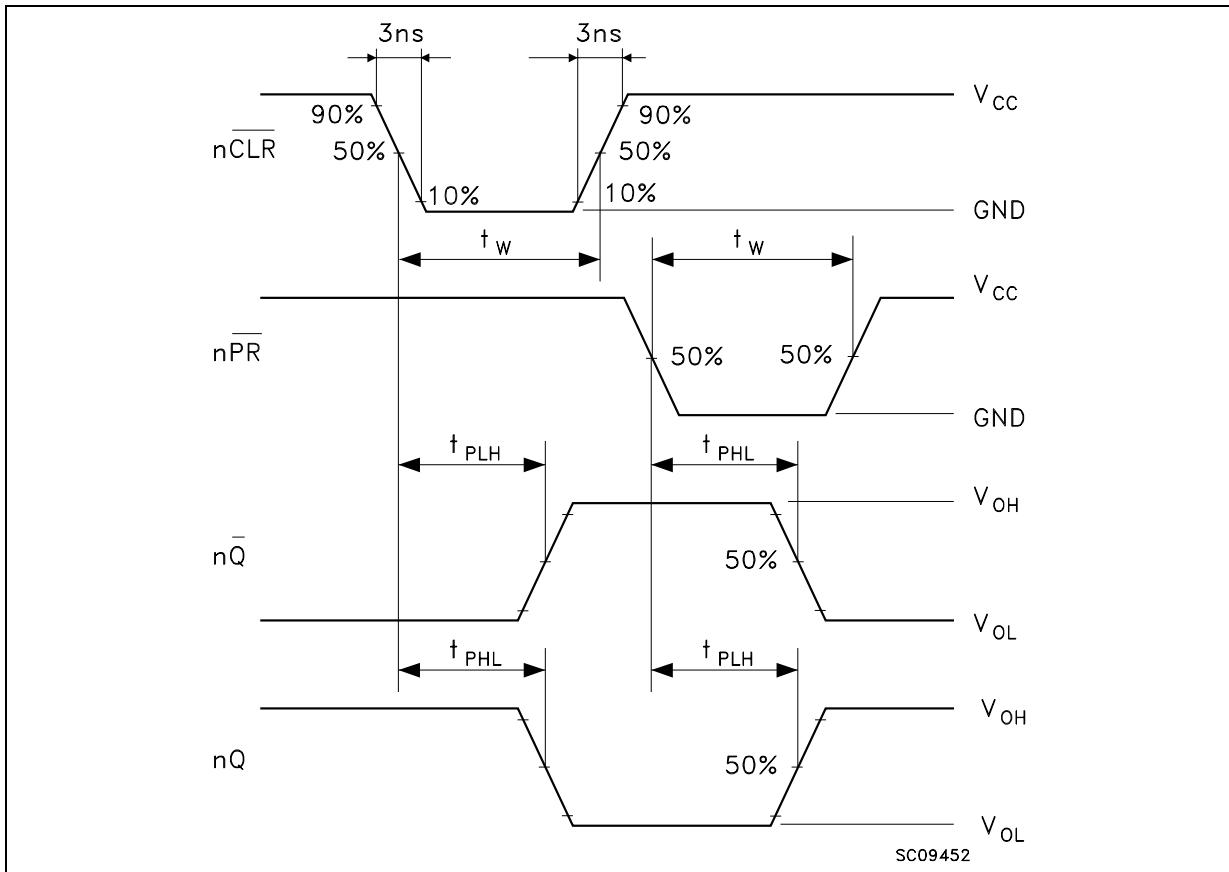
R_L = 500Ω or equivalent

R_T = Z_{OUT} of pulse generator (typically 50Ω)

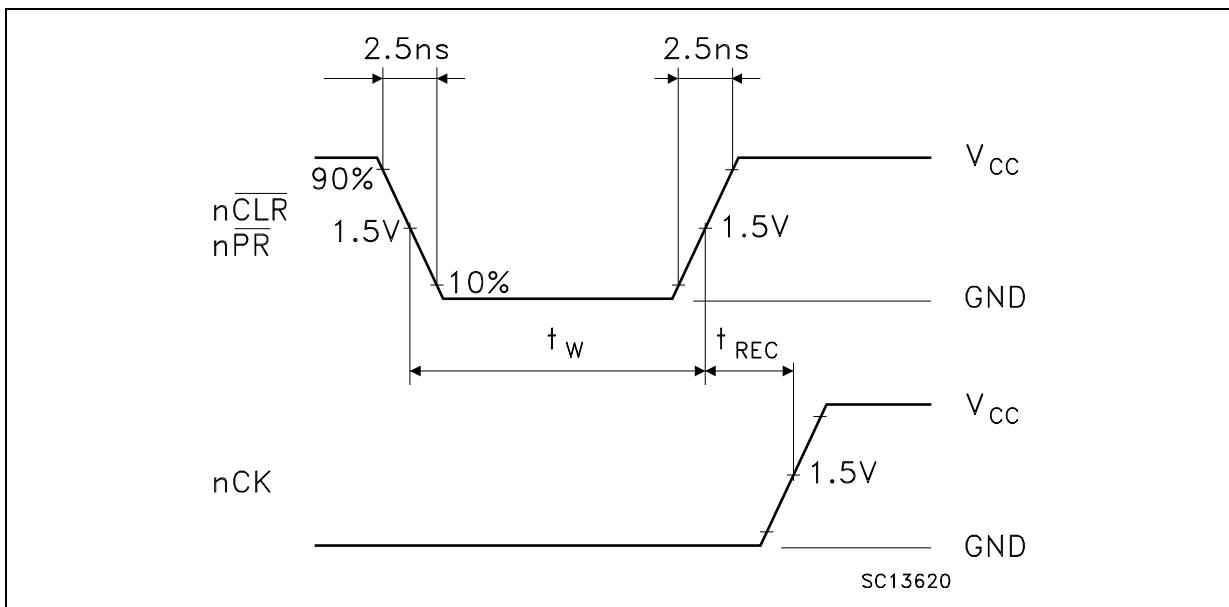
WAVEFORM1:PROPAGATION DELAYS, SETUP AND HOLD TIMES(f=1MHz;50%dutycycle)



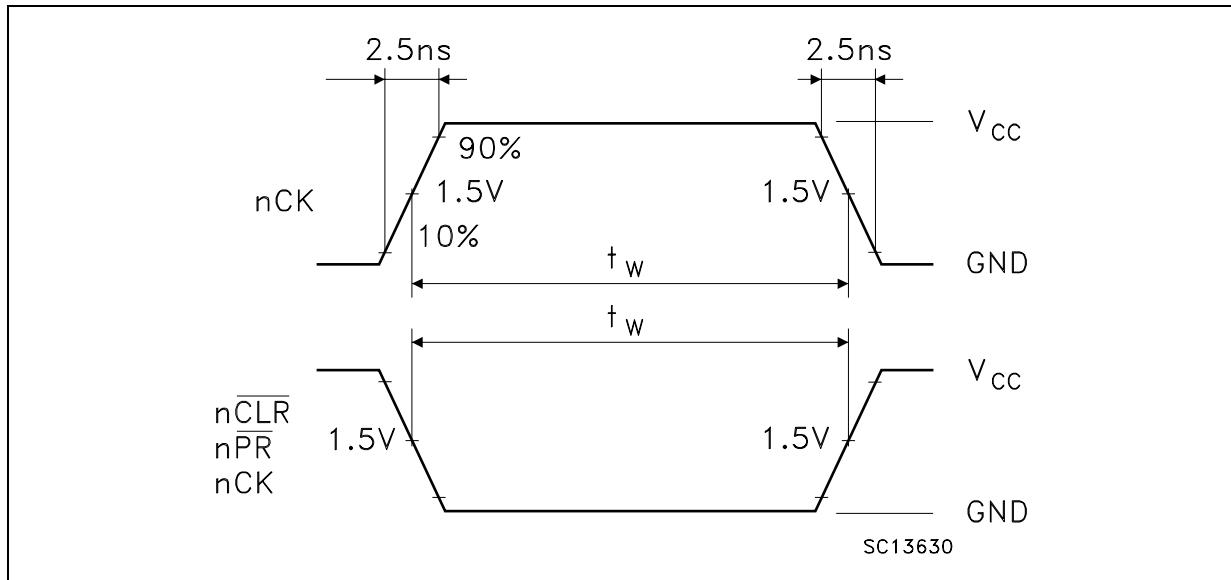
WAVEFORM 2: PROPAGATION DELAYS (f=1MHz; 50% duty cycle)



WAVEFORM 3: RECOVERY TIMES (f=1MHz; 50% duty cycle)

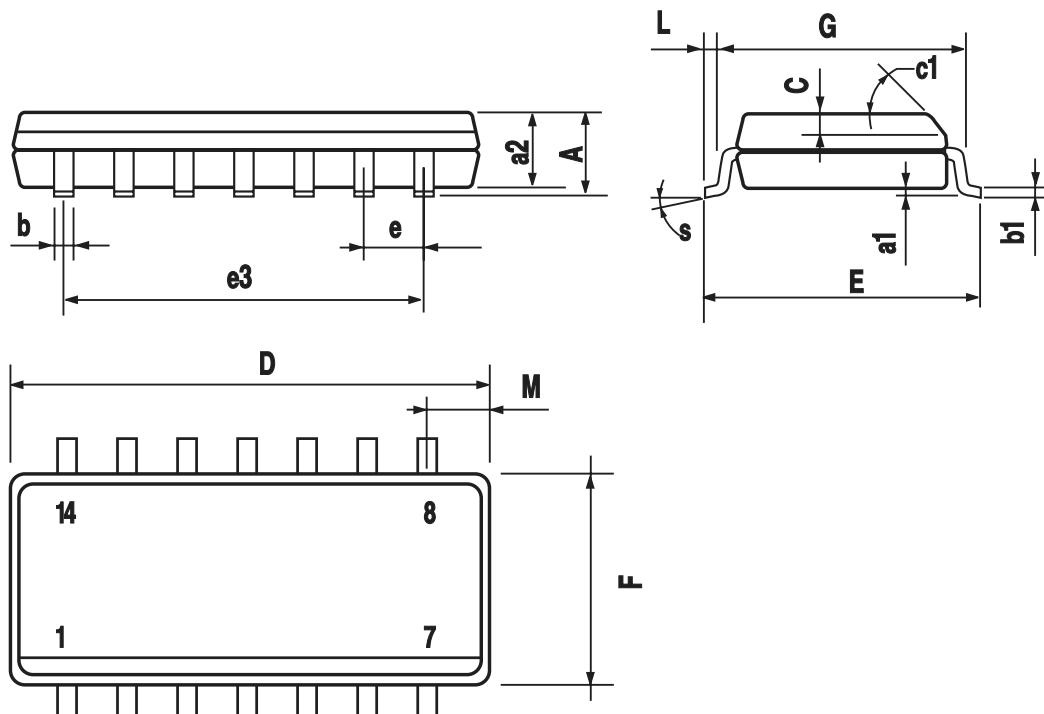


WAVEFORM 4: PULSE WIDTH



SO-14 MECHANICAL DATA

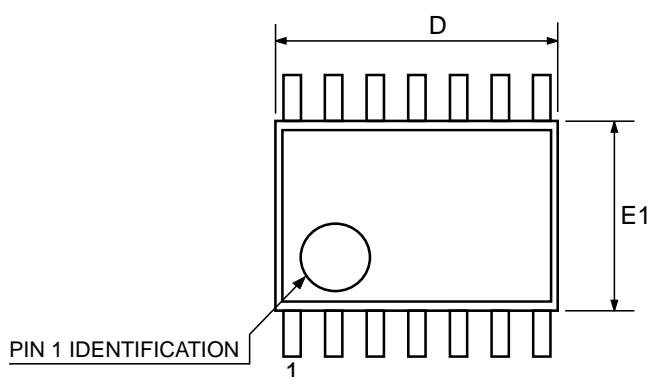
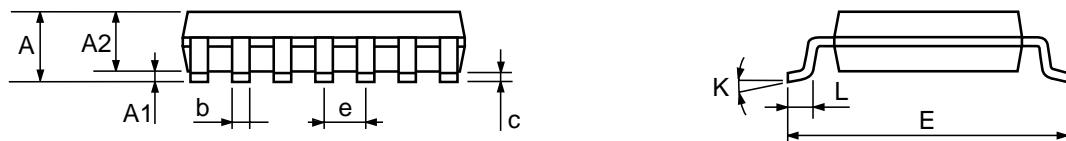
| DIM. | mm. | | | inch | | |
|------|------------|------|------|-------|-------|-------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.75 | | | 0.068 |
| a1 | 0.1 | | 0.2 | 0.003 | | 0.007 |
| a2 | | | 1.65 | | | 0.064 |
| b | 0.35 | | 0.46 | 0.013 | | 0.018 |
| b1 | 0.19 | | 0.25 | 0.007 | | 0.010 |
| C | | 0.5 | | | 0.019 | |
| c1 | 45° (typ.) | | | | | |
| D | 8.55 | | 8.75 | 0.336 | | 0.344 |
| E | 5.8 | | 6.2 | 0.228 | | 0.244 |
| e | | 1.27 | | | 0.050 | |
| e3 | | 7.62 | | | 0.300 | |
| F | 3.8 | | 4.0 | 0.149 | | 0.157 |
| G | 4.6 | | 5.3 | 0.181 | | 0.208 |
| L | 0.5 | | 1.27 | 0.019 | | 0.050 |
| M | | | 0.68 | | | 0.026 |
| S | 8° (max.) | | | | | |



PO13G

TSSOP14 MECHANICAL DATA

| DIM. | mm. | | | inch | | |
|------|------|----------|------|-------|------------|--------|
| | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. |
| A | | | 1.2 | | | 0.047 |
| A1 | 0.05 | | 0.15 | 0.002 | 0.004 | 0.006 |
| A2 | 0.8 | 1 | 1.05 | 0.031 | 0.039 | 0.041 |
| b | 0.19 | | 0.30 | 0.007 | | 0.012 |
| c | 0.09 | | 0.20 | 0.004 | | 0.0089 |
| D | 4.9 | 5 | 5.1 | 0.193 | 0.197 | 0.201 |
| E | 6.2 | 6.4 | 6.6 | 0.244 | 0.252 | 0.260 |
| E1 | 4.3 | 4.4 | 4.48 | 0.169 | 0.173 | 0.176 |
| e | | 0.65 BSC | | | 0.0256 BSC | |
| K | 0° | | 8° | 0° | | 8° |
| L | 0.45 | 0.60 | 0.75 | 0.018 | 0.024 | 0.030 |



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